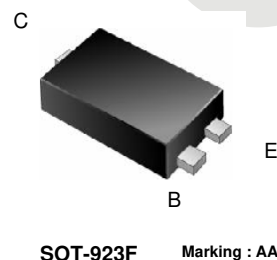**FAIRCHILD**
SEMICONDUCTOR®

February 2008

MMBT3904SL

NPN Epitaxial Silicon Transistor

Features

- General purpose amplifier transistor.
- Ultra small surface mount package for all types(max 0.43mm tall)
- Suitable for general switching & amplification
- Well suited for portable application
- As complementary type, PNP MMBT3906SL is recommended
- Pb free

SOT-923F   Marking : AA

Absolute Maximum Ratings T_a = 25°C unless otherwise noted

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	60	V
V_{CEO}	Collector-Emitter Voltage	40	V
V_{EBO}	Emitter-Base Voltage	6	V
I_C	Collector Current	200	mA
T_J	Junction Temperature	150	°C
T_{STG}	Storage Temperature Range	-55 ~ 150	°C

* 1. These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.
  2. These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics* T_a=25°C unless otherwise noted

Symbol	Parameter	Max	Unit
P_C	Collector Power Dissipation, by $R_{\theta JA}$	227	mW
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	550	°C/W

* Minimum land pad.

Electrical Characteristics* T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Unit
BV_{CBO}	Collector-Base Breakdown Voltage	I_C = 10µA, I_E = 0	60		V
BV_{CEO}	Collector-Emitter Breakdown Voltage	I_C = 1mA, I_B = 0	40		V
BV_{EBO}	Emitter-Base Breakdown Voltage	I_E = 10µA, I_C = 0	6		V
I_{CEX}	Collector Cut-off Current	V_{CE} = 60V, $V_{EB(OFF)}$ = 3V		50	nA
h_{FE}	DC Current Gain	V_{CE} = 1V, I_C = 0.1mA V_{CE} = 1V, I_C = 1mA V_{CE} = 1V, I_C = 10mA V_{CE} = 1V, I_C = 50mA V_{CE} = 1V, I_C = 100mA	40 70 100 60 30	300	
V_{CE} (sat)	Collector-Emitter Saturation Voltage	I_C = 10mA, I_B = 1mA I_C = 50mA, I_B = 5mA		0.2 0.3	V V
V_{BE} (sat)	Base-Emitter Saturation Voltage	I_C = 10mA, I_B = 1mA I_C = 50mA, I_B = 5mA	0.65	0.85 0.95	V V
f_T	Current Gain Bandwidth Product	V_{CE} = 20V, I_C = 10mA, f = 100MHz	300		MHz
C_{ob}	Output Capacitance	V_{CB} = 5V, I_E = 0, f = 1MHz		6	pF
C_{ib}	Input Capacitance	V_{EB} = 0.5V, I_C = 0, f = 1MHz		15	pF
t_d	Delay Time	V_{CC} = 3V, I_C = 10mA I_{B1} =- I_{B2} = 1mA		35	ns
t_r	Rise Time			35	ns
t_s	Storage Time			200	ns
t_f	Fall Time			50	ns

* DC Item are tested by Pulse Test : Pulse Width≤300us, Duty Cycle≤2%

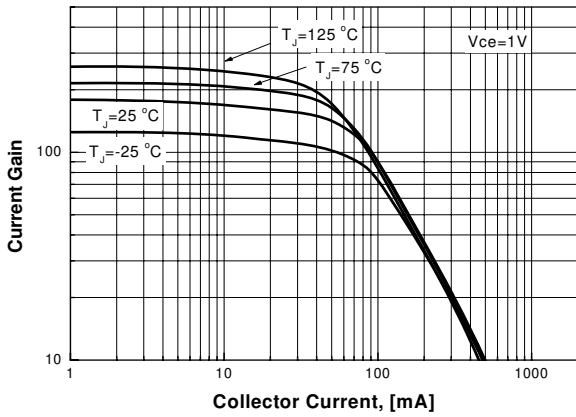## Typical Performance Characteristics

Figure 1. DC Current Gain

Current Gain vs Collector Current, [mA]

T_J=125 $^\circ$C
T_J=75 $^\circ$C
T_J=25 $^\circ$C
T_J=-25 $^\circ$C
Vce=1V

Figure 2. Collector-Emitter Saturation Voltage

Collector-Emitter Voltage,[mV] vs Collector Current, [mA]

Ic=10*Ib
T_J=125 $^\circ$C
T_J=75 $^\circ$C
T_J=25 $^\circ$C
T_J=-25 $^\circ$C
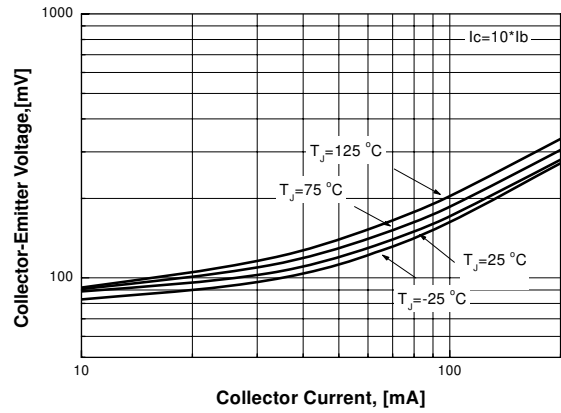
Figure 3. Base- Emitter Saturation Voltage

Base- Emitter Voltage,[mV] vs Collector Current, [mA]

Ic=10*Ib
T_J=25 $^\circ$C
T_J=-25 $^\circ$C
T_J=75 $^\circ$C
T_J=125 $^\circ$C
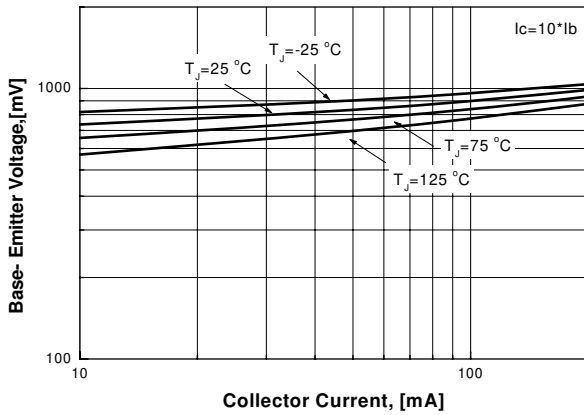
Figure 4. Collector- Base Leakage Current

Base-Collector Leakage Current,[nA] vs Base-Collector Revere Voltage, [V]

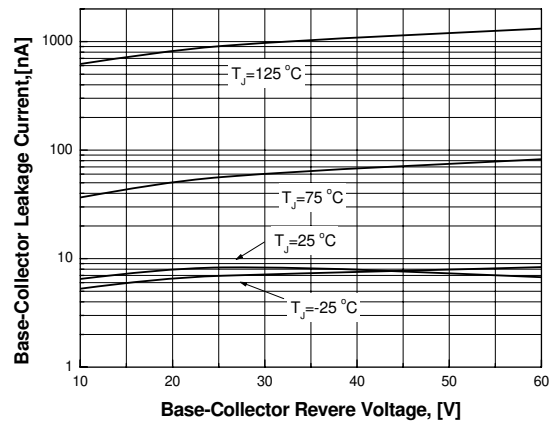T_J=125 $^\circ$C
T_J=75 $^\circ$C
T_J=25 $^\circ$C
T_J=-25 $^\circ$C

Figure 5. Collector- Base Capacitance

Base- Collector Juntion Capacitance, C_{ob}[pF] vs Base- Collector Reverse Voltage, V_{cb}[V]

f=1mhz
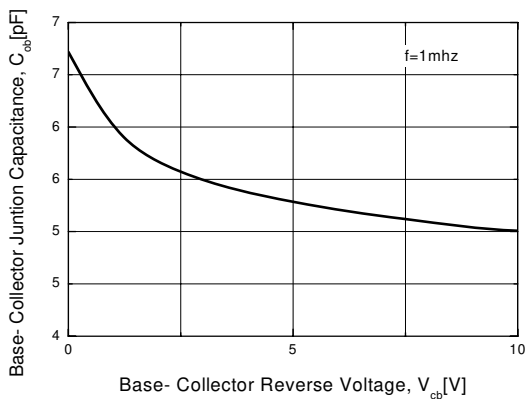
Figure 6. Power Derating

Power Dissipation, [mW] vs Ambient Temperature, T_a[$^\circ$C]
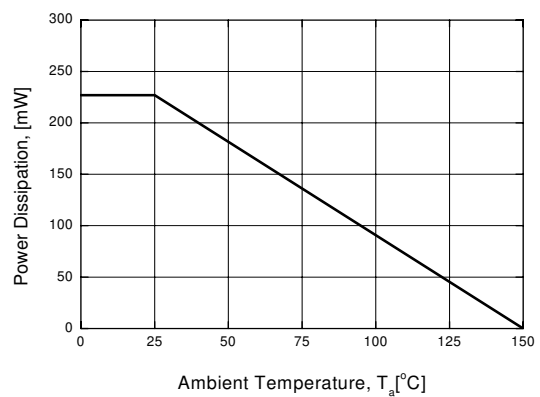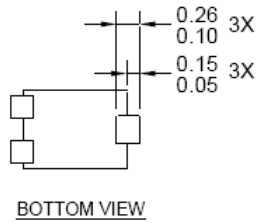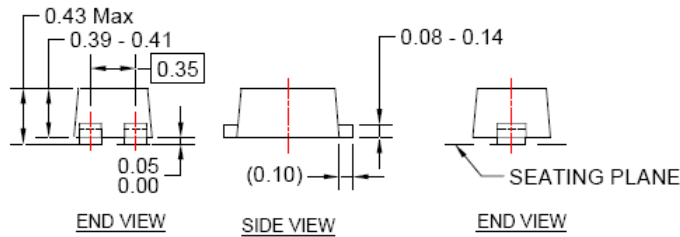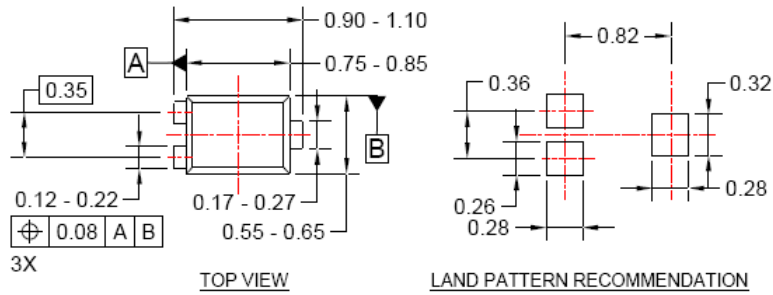
Package Dimensions

SOT-923F

- Case : SOT-923F

- Case Material(Molded Plastic): KTMC1060SC

- UL Flammability classification rating : "V0"

- Moisture Sensitivity level per JESD22-A1113B : MSL 1

- Lead terminals solderable per MIL-STD7502026 /JESD22A121

- Lead Free Plating : Pure Tin(Matte)

TOP VIEW

LAND PATTERN RECOMMENDATION

END VIEW

SIDE VIEW

END VIEW

SEATING PLANE

BOTTOM VIEW

Dimensions in Millimeters

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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